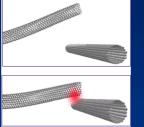


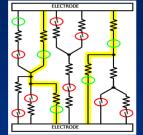


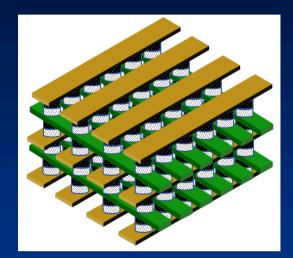
NRAM Carbon Nanotube Memory

Bill Gervasi Principal Systems Architect bilge@Nantero.com







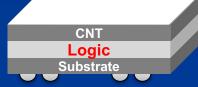


DDR4 DDR5



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Nantero NRAM is a persistent memory using carbon nanotubes to build resistive arrays which can be arranged in a DRAM compatible device or deposited directly on circuits



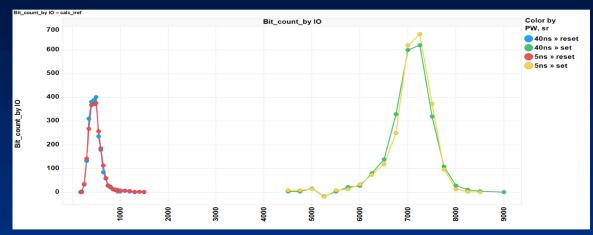
Embedded

HBM

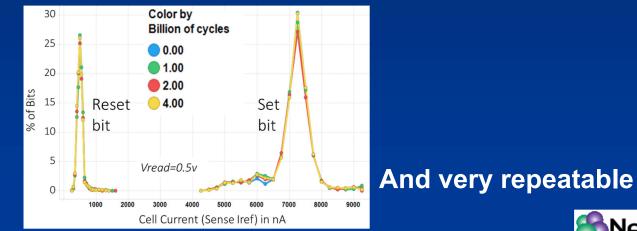






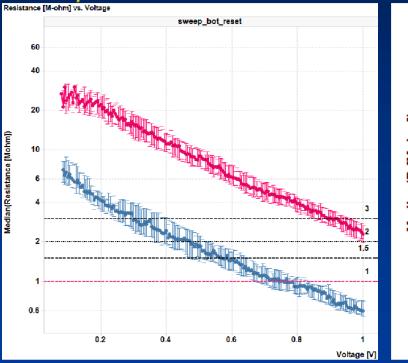


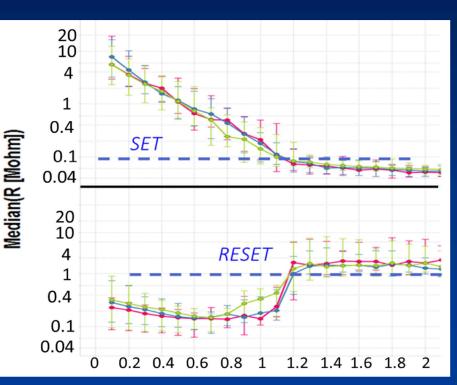
Consistent operation from 40 ns down to 5 ns read/write per cell









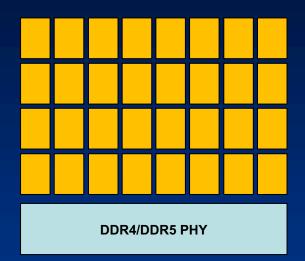


Voltag

е







NRAM crosspoint tiles fit into the DDR protocol at full DRAM speed

No isolation selector diode/transistor needed

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5

TERO



NVRAM scales much better than DRAM

Add layers

New process

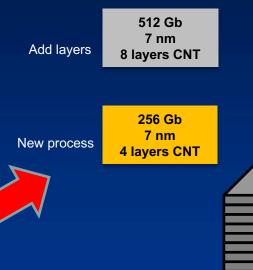
128 Gb

14 nm

8 layers CNT

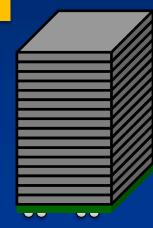
64 Gb 14 nm

4 layers CNT



16 Gb 28 nm 4 layers CNT

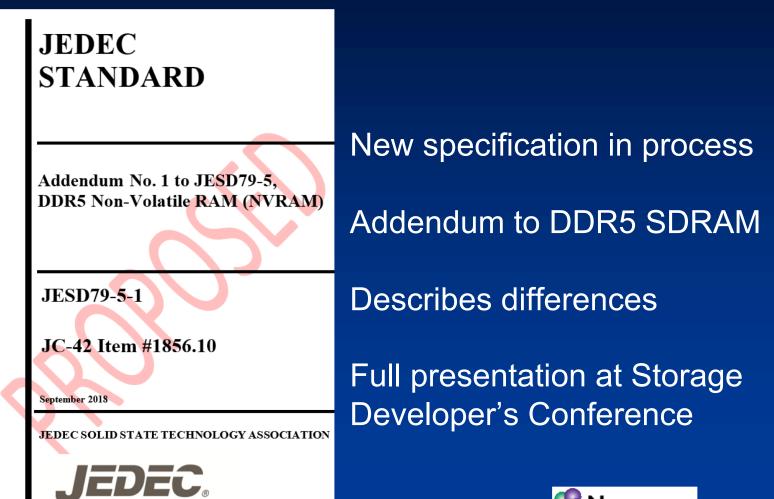
Expect up to 512 Gb/die = 2 TB/package in DDR5 market window



16-die stacks







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NTERO



One step closer to the Holy Grail of end to end...

Data Persistence

Registers

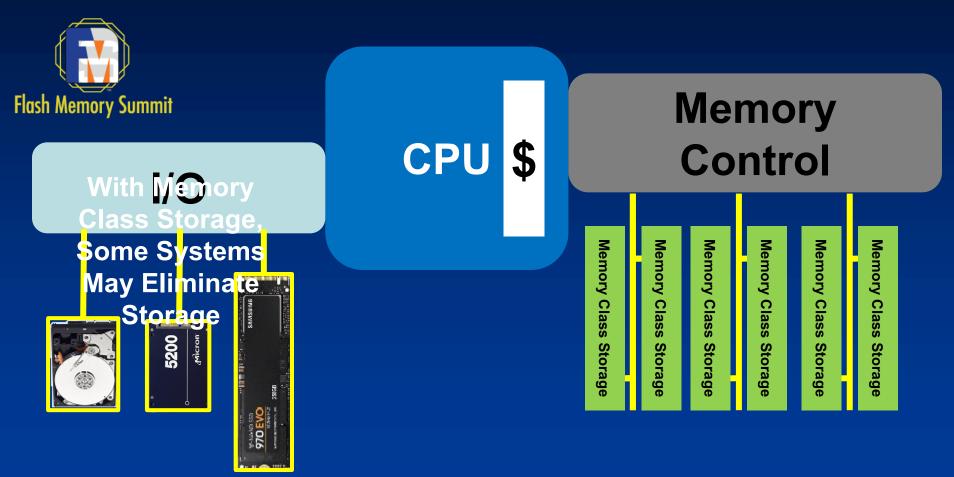
Cache

√ Memory Class Storage

NRAM

NVDIMM \sqrt{SSD} \sqrt{Mag} Optane \sqrt{NVMe} $\sqrt{Hard Drive}$









Thank you

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